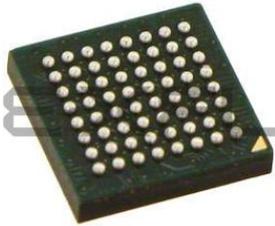


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### What is "[Embedded - Microcontrollers](#)"?



"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I <sup>2</sup> C, SPI, UART/USART, USB
Peripherals	DMA, I <sup>2</sup> S, LCD, LVD, POR, PWM, WDT
Number of I/O	50
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 16x16b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LFBGA
Supplier Device Package	64-MAPBGA (5x5)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl43z128vmp4">https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl43z128vmp4</a>

### Operating Characteristics

- Voltage range: 1.71 to 3.6 V
- Flash write voltage range: 1.71 to 3.6 V
- Temperature range: -40 to 105 °C

### Packages

- 64 LQFP 10mm x 10mm, 0.5mm pitch, 1.6mm thickness
- 64 MAPBGA 5mm x 5mm, 0.5mm pitch, 1.23mm thickness

### Low Power

- Down to 54uA/MHz in very low power run mode
- Down to 1.96uA in VLLS3 mode (RAM + RTC retained)
- Six flexible static modes

### Timers

- One 6-channel Timer/PWM module
- Two 2-channel Timer/PWM modules
- One low-power timer
- Periodic interrupt timer
- Real time clock

### Security and Integrity

- 80-bit unique identification number per chip
- Advanced flash security

### I/O

- Up to 50 general-purpose input/output pins (GPIO) and 6 high-drive pad

## Ordering Information

Product		Memory		Package		IO and ADC channel		
Part number	Marking (Line1/Line2)	Flash (KB)	SRAM (KB)	Pin count	Package	GPIOs	GPIOs (INT/HD) <sup>1</sup>	ADC channels (SE/DP)
MKL43Z128VLH4	MKL43Z128V//LH4	128	16	64	LQFP	50	31/6	16/2
MKL43Z256VLH4	MKL43Z256V//LH4	256	32	64	LQFP	50	31/6	16/2
MKL43Z128VMP4	M43P7V	128	16	64	MAPBGA	50	31/6	16/2
MKL43Z256VMP4	M43P8V	256	32	64	MAPBGA	50	31/6	16/2

1. INT: interrupt pin numbers; HD: high drive pin numbers

## Related Resources

Type	Description	Resource
Selector Guide	The Freescale Solution Advisor is a web-based tool that features interactive application wizards and a dynamic product selector.	<a href="#">Solution Advisor</a>
Product Brief	The Product Brief contains concise overview/summary information to enable quick evaluation of a device for design suitability.	KLX3PB <sup>1</sup>
Reference Manual	The Reference Manual contains a comprehensive description of the structure and function (operation) of a device.	KL43P64M48SF6RM <sup>1</sup>
Data Sheet	The Data Sheet includes electrical characteristics and signal connections.	This document.
Chip Errata	The chip mask set Errata provides additional or corrective information for a particular device mask set.	KINETIS_L_1N71K <sup>1</sup>
Package drawing	Package dimensions are provided in package drawings.	64-LQFP: 98ASS23234W <sup>1</sup> 64 MAPBGA: 98ASA00420D <sup>1</sup>

1. To find the associated resource, go to <http://www.freescale.com> and perform a search using this term.

## 1.4 Voltage and current operating ratings

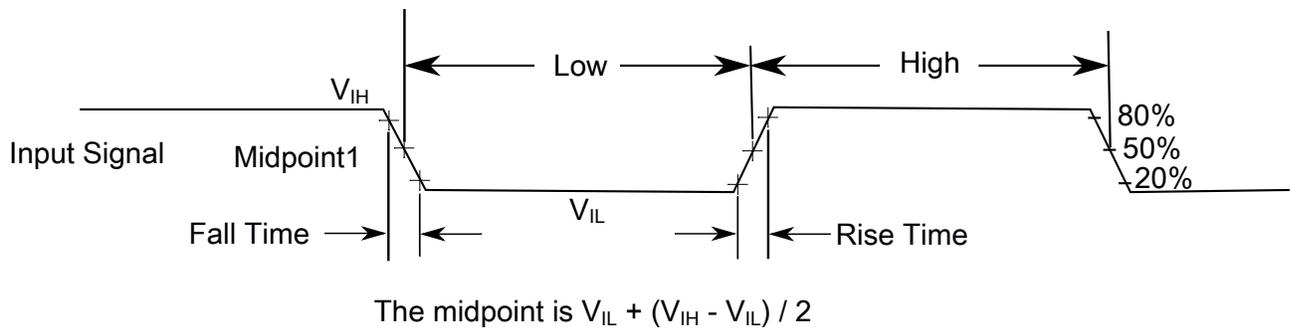
**Table 4. Voltage and current operating ratings**

Symbol	Description	Min.	Max.	Unit
$V_{DD}$	Digital supply voltage	-0.3	3.8	V
$I_{DD}$	Digital supply current	—	120	mA
$V_{IO}$	IO pin input voltage	-0.3	$V_{DD} + 0.3$	V
$I_D$	Instantaneous maximum current single pin limit (applies to all port pins)	-25	25	mA
$V_{DDA}$	Analog supply voltage	$V_{DD} - 0.3$	$V_{DD} + 0.3$	V
$V_{USB\_DP}$	USB_DP input voltage	-0.3	3.63	V
$V_{USB\_DM}$	USB_DM input voltage	-0.3	3.63	V
$V_{REGIN}$	USB regulator input	-0.3	6.0	V

## 2 General

### 2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



**Figure 1. Input signal measurement reference**

All digital I/O switching characteristics, unless otherwise specified, assume that the output pins have the following characteristics.

- $C_L=30$  pF loads
- Slew rate disabled
- Normal drive strength

**Table 9. Power consumption operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>					
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, running CoreMark in Flash all peripheral clock disable 12 MHz core/6 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	2.68	3.32	mA	2
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, running CoreMark in Flash all peripheral clock enable 48 MHz core/24 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	8.08	8.72	mA	2
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, running While(1) loop in flash all peripheral clock disable, 48 MHz core/24 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	3.90	4.54	mA	
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, running While(1) loop in Flash all peripheral clock disable, 24 MHz core/12 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	2.66	3.30	mA	
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, Running While(1) loop in Flash all peripheral clock disable, 12 MHz core/6 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	2.03	2.67	mA	
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, Running While(1) loop in Flash all peripheral clock enable, 48 MHz core/24 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	5.52	6.16	mA	
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, running While(1) loop in SRAM all peripheral clock disable, 48 MHz core/24 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	5.29	5.93	mA	
I <sub>DD_RUN</sub>	Run mode current—48M HIRC mode, running While(1) loop in SRAM all peripheral clock enable, 48 MHz core/24 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>	—	6.91	7.55	mA	

Table continues on the next page...

**Table 9. Power consumption operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li>at 25 °C</li> <li>at 105 °C</li> </ul>					
I <sub>DD_VLPRC</sub> O	Very Low Power Run Core Mark in Flash in Compute Operation mode: Core@4MHz, Flash @1MHz, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	826	907	μA	
I <sub>DD_VLPRC</sub> O	Very-low-power-run While(1) loop in SRAM in compute operation mode— 8 MHz LIRC mode, 4 MHz core / 1 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	405	486	μA	
I <sub>DD_VLPRC</sub> O	Very-low-power run While(1) loop in SRAM in compute operation mode:—2 MHz LIRC mode, 2 MHz core / 0.5 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	154	235	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current— 2 MHz LIRC mode, While(1) loop in flash all peripheral clock disable, 2 MHz core / 0.5 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	108	189	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current— 2 MHz LIRC mode, While(1) loop in flash all peripheral clock disable, 125 kHz core / 31.25 kHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	39	120	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current— 8 MHz LIRC mode, While(1) loop in flash all peripheral clock disable, 4 MHz core / 1 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	249	330	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current— 8 MHz LIRC mode, While(1) loop in flash all peripheral clock enable, 4 MHz core / 1 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	337	418	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current— 8 MHz LIRC mode, While(1) loop in SRAM in all peripheral clock disable, 4 MHz core / 1 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	416	497	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current— 8 MHz LIRC mode, While(1) loop in SRAM all peripheral clock enable, 4 MHz core / 1 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	494	575	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current—2 MHz LIRC mode, While(1) loop in SRAM in all peripheral clock disable, 2 MHz core / 0.5 MHz flash, V <sub>DD</sub> = 3.0 V <ul style="list-style-type: none"> <li>at 25 °C</li> </ul>	—	166	247	μA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current—2 MHz LIRC mode, While(1) loop in SRAM all peripheral clock					

Table continues on the next page...

**Table 9. Power consumption operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I <sub>DD_VLLS3</sub>	Very-low-leakage stop mode 3 current with RTC current, at 1.8 V <ul style="list-style-type: none"> <li>• at 25 °C and below</li> <li>• at 50 °C</li> <li>• at 70 °C</li> <li>• at 85 °C</li> <li>• at 105 °C</li> </ul>	—	1.96	2.36	μA	3
I <sub>DD_VLLS1</sub>	Very-low-leakage stop mode 1 current all peripheral disabled at 3.0 V <ul style="list-style-type: none"> <li>• at 25 °C and below</li> <li>• at 50 °C</li> <li>• at 70 °C</li> <li>• at 85 °C</li> <li>• at 105 °C</li> </ul>	—	0.66	0.80	μA	
I <sub>DD_VLLS1</sub>	Very-low-leakage stop mode 1 current RTC enabled at 3.0 V <ul style="list-style-type: none"> <li>• at 25 °C and below</li> <li>• at 50 °C</li> <li>• at 70 °C</li> <li>• at 85 °C</li> <li>• at 105 °C</li> </ul>	—	1.26	1.40	μA	3
I <sub>DD_VLLS1</sub>	Very-low-leakage stop mode 1 current RTC enabled at 1.8 V <ul style="list-style-type: none"> <li>• at 25 °C and below</li> <li>• at 50 °C</li> <li>• at 70 °C</li> <li>• at 85 °C</li> <li>• at 105 °C</li> </ul>	—	1.16	1.30	μA	3
I <sub>DD_VLLS0</sub>	Very-low-leakage stop mode 0 current all peripheral disabled (SMC_STOPCTRL[PORPO] = 0) at 3.0 V <ul style="list-style-type: none"> <li>• at 25 °C and below</li> <li>• at 50 °C</li> <li>• at 70 °C</li> <li>• at 85 °C</li> <li>• at 105 °C</li> </ul>	—	0.35	0.47	μA	
I <sub>DD_VLLS0</sub>	Very-low-leakage stop mode 0 current all peripheral disabled (SMC_STOPCTRL[PORPO] = 1) at 3 V					

**Table 9. Power consumption operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li>at 25 °C and below</li> <li>at 50 °C</li> <li>at 70 °C</li> <li>at 85 °C</li> <li>at 105 °C</li> </ul>	—	0.18	0.28	μA	
		—	1.09	1.31		
		—	2.25	2.94		
		—	4.25	5.10		
		—	15.95	19.10		

1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.
2. MCG\_Lite configured for HIRC mode. CoreMark benchmark compiled using IAR 7.10 with optimization level high, optimized for balanced.
3. RTC uses external 32 kHz crystal as clock source, and the current includes ERCLK32K power consumption.

**Table 10. Low power mode peripheral adders — typical value**

Symbol	Description	Temperature (°C)						Unit
		-40	25	50	70	85	105	
I <sub>IRC8MHz</sub>	8 MHz internal reference clock (IRC) adder. Measured by entering STOP or VLPS mode with 8 MHz IRC enabled, MCG_SC[FCRDIV]=000b, MCG_MC[LIRC_DIV2]=000b.	93	93	93	93	93	93	μA
I <sub>IRC2MHz</sub>	2 MHz internal reference clock (IRC) adder. Measured by entering STOP mode with the 2 MHz IRC enabled, MCG_SC[FCRDIV]=000b, MCG_MC[LIRC_DIV2]=000b.	29	29	29	29	29	29	μA
I <sub>EREFSTEN4MHz</sub>	External 4 MHz crystal clock adder. Measured by entering STOP or VLPS mode with the crystal enabled.	206	224	230	238	245	253	μA
I <sub>EREFSTEN32KHz</sub>	External 32 kHz crystal clock adder by means of the OSC0_CR[EREFSTEN and EREFSTEN] bits. Measured by entering all modes with the crystal enabled. <ul style="list-style-type: none"> <li>VLLS1</li> <li>VLLS3</li> <li>LLS</li> <li>VLPS</li> <li>STOP</li> </ul>	440	490	540	560	570	580	nA
		440	490	540	560	570	580	
		490	490	540	560	570	680	
		510	560	560	560	610	680	
		510	560	560	560	610	680	
I <sub>LPTMR</sub>	LPTMR peripheral adder measured by placing the device in VLLS1 mode with LPTMR enabled using LPO.	30	30	30	85	100	200	

Table continues on the next page...

**Table 10. Low power mode peripheral adders — typical value (continued)**

Symbol	Description	Temperature (°C)						Unit
		-40	25	50	70	85	105	
								nA
I <sub>CMP</sub>	CMP peripheral adder measured by placing the device in VLLS1 mode with CMP enabled using the 6-bit DAC and a single external input for compare. Includes 6-bit DAC power consumption.	22	22	22	22	22	22	μA
I <sub>UART</sub>	UART peripheral adder measured by placing the device in STOP or VLPS mode with selected clock source waiting for RX data at 115200 baud rate. Includes selected clock source power consumption. <ul style="list-style-type: none"> <li>• IRC8M (8 MHz internal reference clock)</li> <li>• IRC2M (2 MHz internal reference clock)</li> </ul>	114	114	114	114	114	114	μA
		34	34	34	34	34	34	
I <sub>TPM</sub>	TPM peripheral adder measured by placing the device in STOP or VLPS mode with selected clock source configured for output compare generating 100 Hz clock signal. No load is placed on the I/O generating the clock signal. Includes selected clock source and I/O switching currents. <ul style="list-style-type: none"> <li>• IRC8M (8 MHz internal reference clock)</li> <li>• IRC2M (2 MHz internal reference clock)</li> </ul>	147	147	147	147	147	147	μA
		42	42	42	42	42	42	
I <sub>BG</sub>	Bandgap adder when BGEN bit is set and device is placed in VLPx or VLLSx mode.	45	45	45	45	45	45	μA
I <sub>ADC</sub>	ADC peripheral adder combining the measured values at V <sub>DD</sub> and V <sub>DDA</sub> by placing the device in STOP or VLPS mode. ADC is configured for low power mode using the internal clock and continuous conversions.	330	330	330	330	330	330	μA
I <sub>LCD</sub>	LCD peripheral adder measured by placing the device in VLLS1 mode with external 32 kHz crystal enabled by means of the OSC0_CR[EREFSTEN, EREFSTEN] bits. VIREG disabled, resistor bias network enabled, 1/8 duty cycle, 8 x 36 configuration for driving 288 Segments, 32 Hz frame rate, no LCD glass connected. Includes ERCLK32K (32 kHz external crystal) power consumption.	4.5	4.5	4.5	4.5	4.5	4.5	μA

**Table 18. IRC48M specification (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$T_j$	Period jitter (RMS)	—	35	150	ps	—
$T_{su}$	Startup time	—	2	3	$\mu$ s	—

1. The maximum value represents characterized results equivalent to mean plus or minus three times the standard deviation (mean  $\pm$ 3sigma).

**Table 19. IRC8M/2M specification**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$I_{DD\_2M}$	Supply current in 2 MHz mode	—	14	17	$\mu$ A	—
$I_{DD\_8M}$	Supply current in 8 MHz mode	—	30	35	$\mu$ A	—
$f_{IRC\_2M}$	Output frequency	—	2	—	MHz	—
$f_{IRC\_8M}$	Output frequency	—	8	—	MHz	—
$f_{IRC\_T\_2M}$	Output frequency range (trimmed)	—	—	$\pm$ 3	% $f_{IRC}$	—
$f_{IRC\_T\_8M}$	Output frequency range (trimmed)	—	—	$\pm$ 3	% $f_{IRC}$	—
$T_{su\_2M}$	Startup time	—	—	12.5	$\mu$ s	—
$T_{su\_8M}$	Startup time	—	—	12.5	$\mu$ s	—

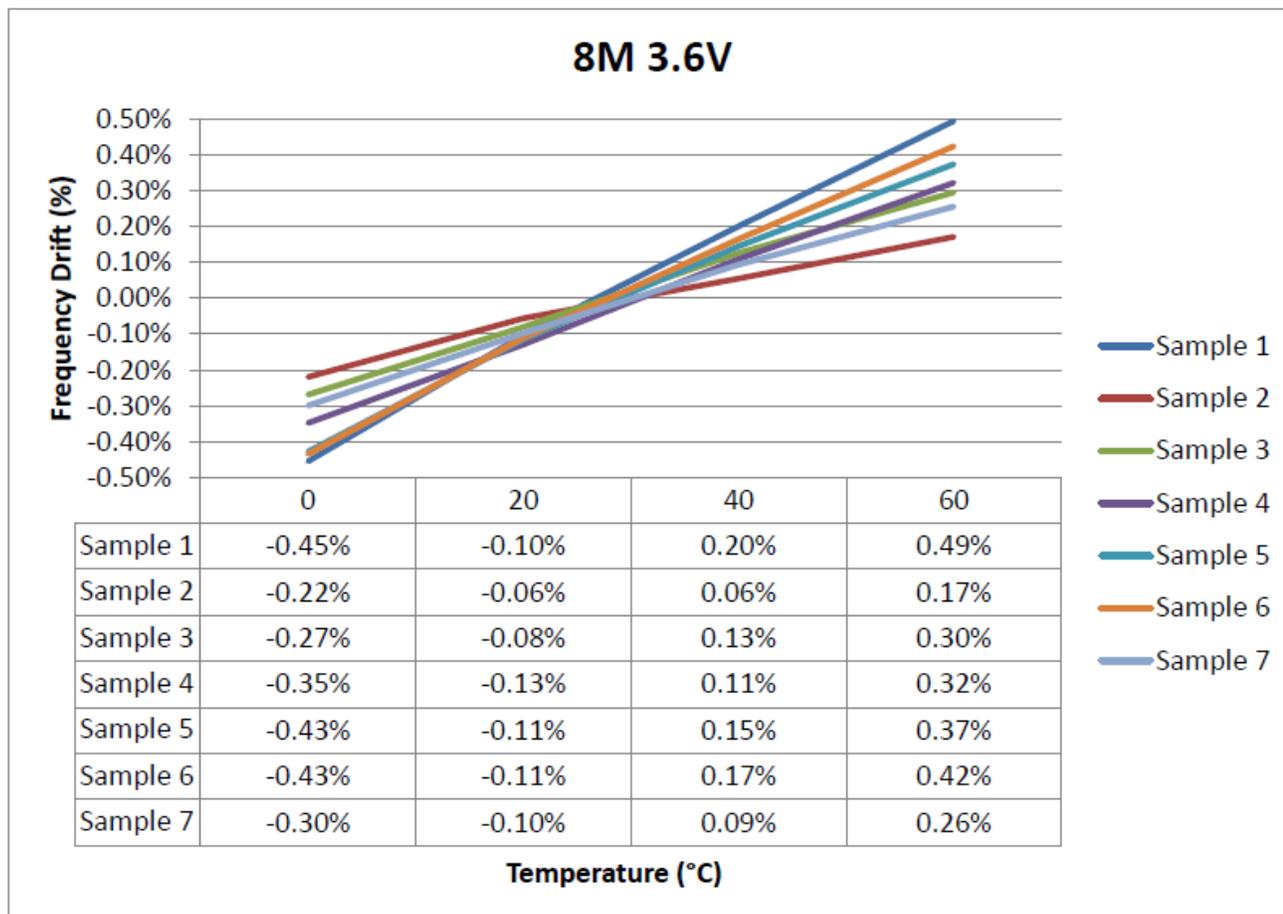


Figure 6. IRC8M Frequency Drift vs Temperature curve

### 3.3.2 Oscillator electrical specifications

#### 3.3.2.1 Oscillator DC electrical specifications

Table 20. Oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>DD</sub>	Supply voltage	1.71	—	3.6	V	
I <sub>DDOSC</sub>	Supply current — low-power mode (HGO=0)					1
	• 32 kHz	—	500	—	nA	
	• 4 MHz	—	200	—	μA	
	• 8 MHz (RANGE=01)	—	300	—	μA	
	• 16 MHz	—	950	—	μA	
		—	1.2	—	mA	

Table continues on the next page...

### 3.4.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

**Table 22. NVM program/erase timing specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{hvpgm4}$	Longword Program high-voltage time	—	7.5	18	$\mu$ s	—
$t_{hversscr}$	Sector Erase high-voltage time	—	13	113	ms	1
$t_{hversblk128k}$	Erase Block high-voltage time for 128 KB	—	52	452	ms	1

1. Maximum time based on expectations at cycling end-of-life.

### 3.4.1.2 Flash timing specifications — commands

**Table 23. Flash command timing specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{rd1blk128k}$	Read 1s Block execution time • 128 KB program flash	—	—	1.7	ms	1
$t_{rd1sec1k}$	Read 1s Section execution time (flash sector)	—	—	60	$\mu$ s	1
$t_{pgmchk}$	Program Check execution time	—	—	45	$\mu$ s	1
$t_{rdsrc}$	Read Resource execution time	—	—	30	$\mu$ s	1
$t_{pgm4}$	Program Longword execution time	—	65	145	$\mu$ s	—
$t_{ersblk128k}$	Erase Flash Block execution time • 128 KB program flash	—	88	600	ms	2
$t_{ersscr}$	Erase Flash Sector execution time	—	14	114	ms	2
$t_{rd1all}$	Read 1s All Blocks execution time	—	—	1.8	ms	1
$t_{rdonce}$	Read Once execution time	—	—	25	$\mu$ s	1
$t_{pgmonce}$	Program Once execution time	—	65	—	$\mu$ s	—
$t_{ersall}$	Erase All Blocks execution time	—	175	1300	ms	2
$t_{vfykey}$	Verify Backdoor Access Key execution time	—	—	30	$\mu$ s	1
$t_{ersallu}$	Erase All Blocks Unsecure execution time	—	175	1300	ms	2

1. Assumes 25 MHz flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.

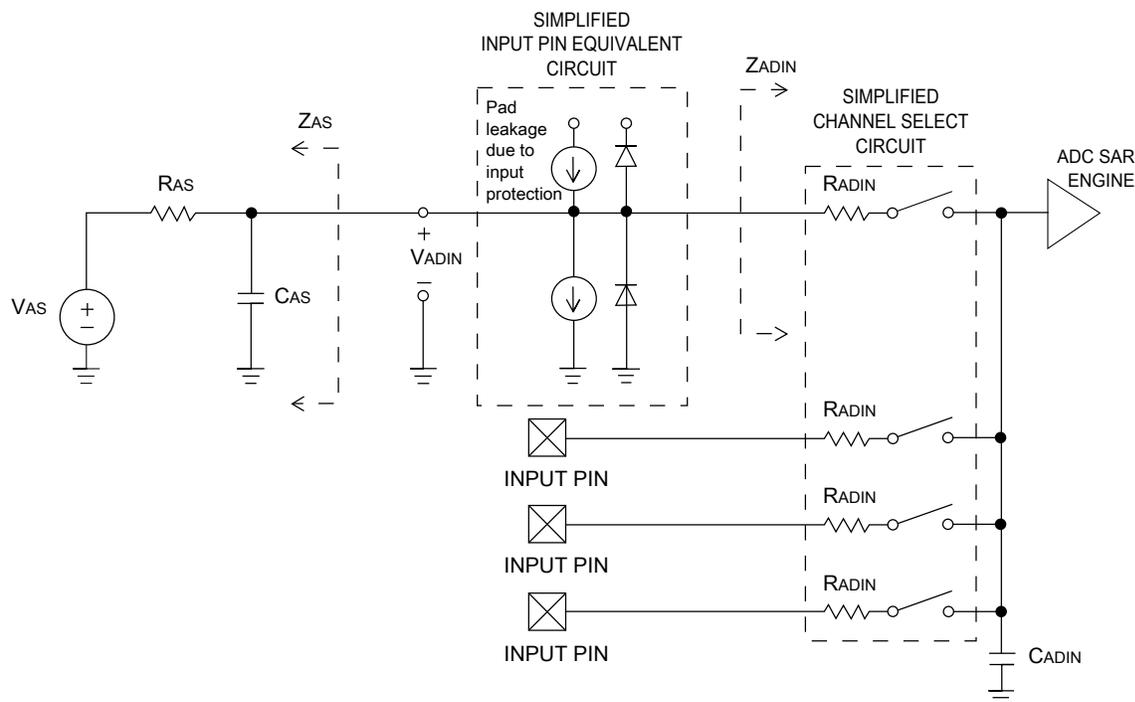


Figure 7. ADC input impedance equivalency diagram

### 3.6.1.2 16-bit ADC electrical characteristics

Table 27. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
$I_{DDA\_ADC}$	Supply current		0.215	—	1.7	mA	3
$f_{ADACK}$	ADC asynchronous clock source	• ADLPC = 1, ADHSC = 0	1.2	2.4	3.9	MHz	$t_{ADACK} = 1/f_{ADACK}$
		• ADLPC = 1, ADHSC = 1	2.4	4.0	6.1	MHz	
		• ADLPC = 0, ADHSC = 0	3.0	5.2	7.3	MHz	
		• ADLPC = 0, ADHSC = 1	4.4	6.2	9.5	MHz	
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	• 12-bit modes • <12-bit modes	—	±4 ±1.4	±6.8 ±2.1	LSB <sup>4</sup>	5
DNL	Differential non-linearity	• 12-bit modes • <12-bit modes	—	±0.7 ±0.2	-1.1 to +1.9 -0.3 to 0.5	LSB <sup>4</sup>	5
INL	Integral non-linearity	• 12-bit modes • <12-bit modes	—	±1.0 ±0.5	-2.7 to +1.9	LSB <sup>4</sup>	5

Table continues on the next page...

**Table 27. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ ) (continued)**

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
					-0.7 to +0.5		
$E_{FS}$	Full-scale error	<ul style="list-style-type: none"> <li>12-bit modes</li> <li>&lt;12-bit modes</li> </ul>	—	-4	-5.4	LSB <sup>4</sup>	$V_{ADIN} = V_{DDA}$ <sup>5</sup>
$E_Q$	Quantization error	<ul style="list-style-type: none"> <li>16-bit modes</li> <li>≤13-bit modes</li> </ul>	—	-1 to 0	—	LSB <sup>4</sup>	
ENOB	Effective number of bits	16-bit differential mode					
		<ul style="list-style-type: none"> <li>Avg = 32</li> <li>Avg = 4</li> </ul>	12.8	14.5	—	bits	6
			11.9	13.8	—	bits	
		16-bit single-ended mode					
<ul style="list-style-type: none"> <li>Avg = 32</li> <li>Avg = 4</li> </ul>	12.2	13.9	—	bits			
			11.4	13.1	—		
SINAD	Signal-to-noise plus distortion	See ENOB	6.02 × ENOB + 1.76			dB	
THD	Total harmonic distortion	16-bit differential mode				dB	7
		<ul style="list-style-type: none"> <li>Avg = 32</li> </ul>	—	-94	—	dB	
		16-bit single-ended mode					
		<ul style="list-style-type: none"> <li>Avg = 32</li> </ul>	—	-85	—		
SFDR	Spurious free dynamic range	16-bit differential mode				dB	7
		<ul style="list-style-type: none"> <li>Avg = 32</li> </ul>	82	95	—	dB	
		16-bit single-ended mode					
		<ul style="list-style-type: none"> <li>Avg = 32</li> </ul>	78	90	—		
$E_{IL}$	Input leakage error		$I_{in} \times R_{AS}$			mV	$I_{in}$ = leakage current (refer to the MCU's voltage and current operating ratings)
	Temp sensor slope	Across the full temperature range of the device	1.55	1.62	1.69	mV/°C	8
$V_{TEMP25}$	Temp sensor voltage	25 °C	706	716	726	mV	8

 1. All accuracy numbers assume the ADC is calibrated with  $V_{REFH} = V_{DDA}$

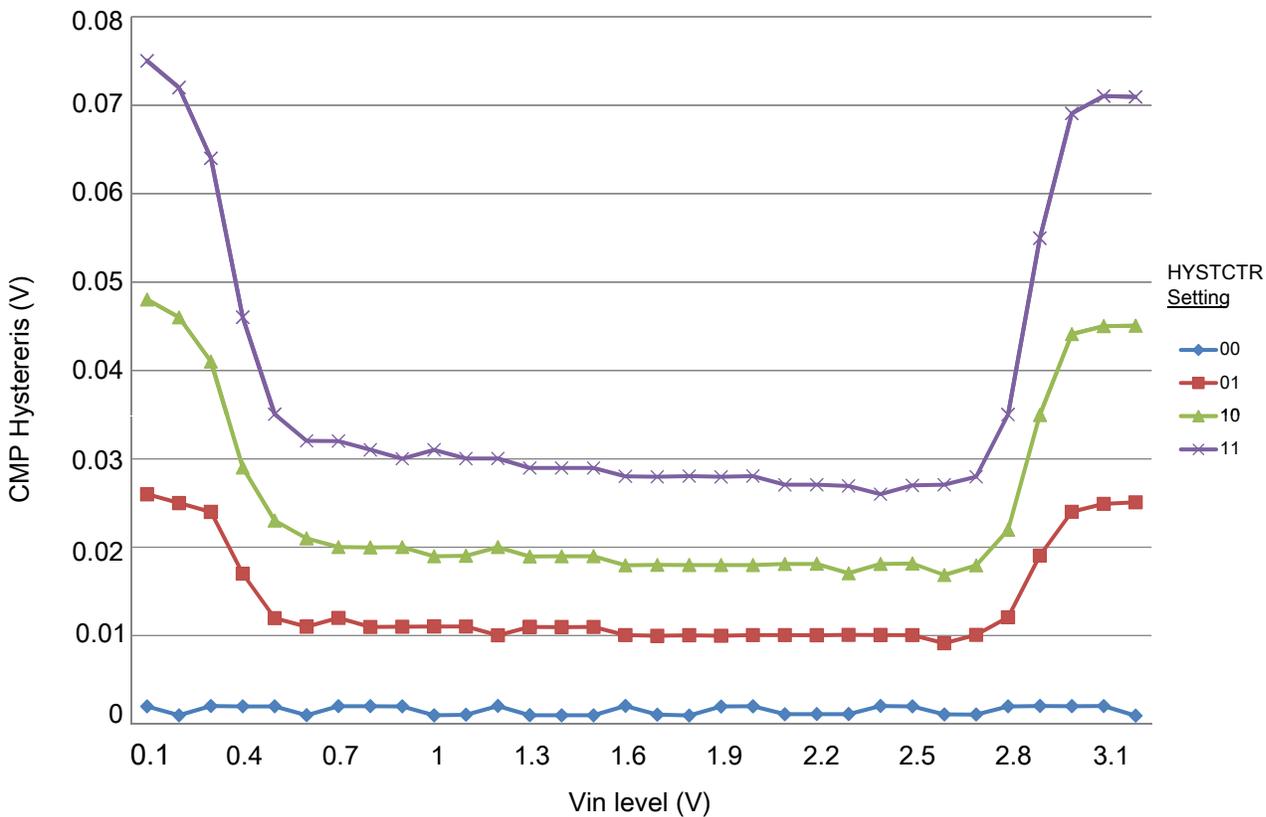


Figure 10. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 0)

### 3.6.4.2 12-bit DAC operating behaviors

**Table 34. 12-bit DAC operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$I_{DDA\_DACLP}$	Supply current — low-power mode	—	—	250	$\mu\text{A}$	
$I_{DDA\_DACHP}$	Supply current — high-speed mode	—	—	900	$\mu\text{A}$	
$t_{DACLP}$	Full-scale settling time (0x080 to 0xF7F) — low-power mode	—	100	200	$\mu\text{s}$	1
$t_{DACHP}$	Full-scale settling time (0x080 to 0xF7F) — high-power mode	—	15	30	$\mu\text{s}$	1
$t_{CCDACLP}$	Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode	—	0.7	1	$\mu\text{s}$	1
$V_{dacoutl}$	DAC output voltage range low — high-speed mode, no load, DAC set to 0x000	—	—	100	mV	
$V_{dacouth}$	DAC output voltage range high — high-speed mode, no load, DAC set to 0xFFFF	$V_{DACR} - 100$	—	$V_{DACR}$	mV	
INL	Integral non-linearity error — high speed mode	—	—	$\pm 8$	LSB	2
DNL	Differential non-linearity error — $V_{DACR} > 2\text{ V}$	—	—	$\pm 1$	LSB	3
DNL	Differential non-linearity error — $V_{DACR} = V_{REF\_OUT}$	—	—	$\pm 1$	LSB	4
$V_{OFFSET}$	Offset error	—	$\pm 0.4$	$\pm 0.8$	%FSR	5
$E_G$	Gain error	—	$\pm 0.1$	$\pm 0.6$	%FSR	5
PSRR	Power supply rejection ratio, $V_{DDA} \geq 2.4\text{ V}$	60	—	90	dB	
$T_{CO}$	Temperature coefficient offset voltage	—	3.7	—	$\mu\text{V}/\text{C}$	6
$T_{GE}$	Temperature coefficient gain error	—	0.000421	—	%FSR/C	
$R_{op}$	Output resistance (load = 3 k $\Omega$ )	—	—	250	$\Omega$	
SR	Slew rate -80h → F7Fh → 80h <ul style="list-style-type: none"> <li>• High power (SP<sub>HP</sub>)</li> <li>• Low power (SP<sub>LP</sub>)</li> </ul>	1.2 0.05	1.7 0.12	— —	V/ $\mu\text{s}$	
BW	3dB bandwidth <ul style="list-style-type: none"> <li>• High power (SP<sub>HP</sub>)</li> <li>• Low power (SP<sub>LP</sub>)</li> </ul>	550 40	— —	— —	kHz	

1. Settling within  $\pm 1$  LSB
2. The INL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV
3. The DNL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV
4. The DNL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV with  $V_{DDA} > 2.4\text{ V}$
5. Calculated by a best fit curve from  $V_{SS} + 100$  mV to  $V_{DACR} - 100$  mV
6.  $V_{DDA} = 3.0\text{ V}$ , reference select set for  $V_{DDA}$  (DACx\_CO:DACRFS = 1), high power mode (DACx\_CO:LPEN = 0), DAC set to 0x800, temperature range is across the full range of the device

### 3.8.3 SPI switching specifications

The Serial Peripheral Interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. See the SPI chapter of the chip's Reference Manual for information about the modified transfer formats used for communicating with slower peripheral devices.

All timing is shown with respect to 20%  $V_{DD}$  and 80%  $V_{DD}$  thresholds, unless noted, as well as input signal transitions of 3 ns and a 30 pF maximum load on all SPI pins.

**Table 36. SPI master mode timing on slew rate disabled pads**

Num.	Symbol	Description	Min.	Max.	Unit	Note
1	$f_{op}$	Frequency of operation	$f_{periph}/2048$	$f_{periph}/2$	Hz	1
2	$t_{SPSCK}$	SPSCK period	$2 \times t_{periph}$	$2048 \times t_{periph}$	ns	2
3	$t_{Lead}$	Enable lead time	1/2	—	$t_{SPSCK}$	—
4	$t_{Lag}$	Enable lag time	1/2	—	$t_{SPSCK}$	—
5	$t_{WSPSCK}$	Clock (SPSCK) high or low time	$t_{periph} - 30$	$1024 \times t_{periph}$	ns	—
6	$t_{SU}$	Data setup time (inputs)	18	—	ns	—
7	$t_{HI}$	Data hold time (inputs)	0	—	ns	—
8	$t_v$	Data valid (after SPSCK edge)	—	15	ns	—
9	$t_{HO}$	Data hold time (outputs)	0	—	ns	—
10	$t_{RI}$	Rise time input	—	$t_{periph} - 25$	ns	—
	$t_{FI}$	Fall time input				
11	$t_{RO}$	Rise time output	—	25	ns	—
	$t_{FO}$	Fall time output				

1. For SPI0  $f_{periph}$  is the bus clock ( $f_{BUS}$ ). For SPI1  $f_{periph}$  is the system clock ( $f_{SYS}$ ).
2.  $t_{periph} = 1/f_{periph}$

**Table 37. SPI master mode timing on slew rate enabled pads**

Num.	Symbol	Description	Min.	Max.	Unit	Note
1	$f_{op}$	Frequency of operation	$f_{periph}/2048$	$f_{periph}/2$	Hz	1
2	$t_{SPSCK}$	SPSCK period	$2 \times t_{periph}$	$2048 \times t_{periph}$	ns	2
3	$t_{Lead}$	Enable lead time	1/2	—	$t_{SPSCK}$	—
4	$t_{Lag}$	Enable lag time	1/2	—	$t_{SPSCK}$	—
5	$t_{WSPSCK}$	Clock (SPSCK) high or low time	$t_{periph} - 30$	$1024 \times t_{periph}$	ns	—
6	$t_{SU}$	Data setup time (inputs)	96	—	ns	—
7	$t_{HI}$	Data hold time (inputs)	0	—	ns	—

Table continues on the next page...

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

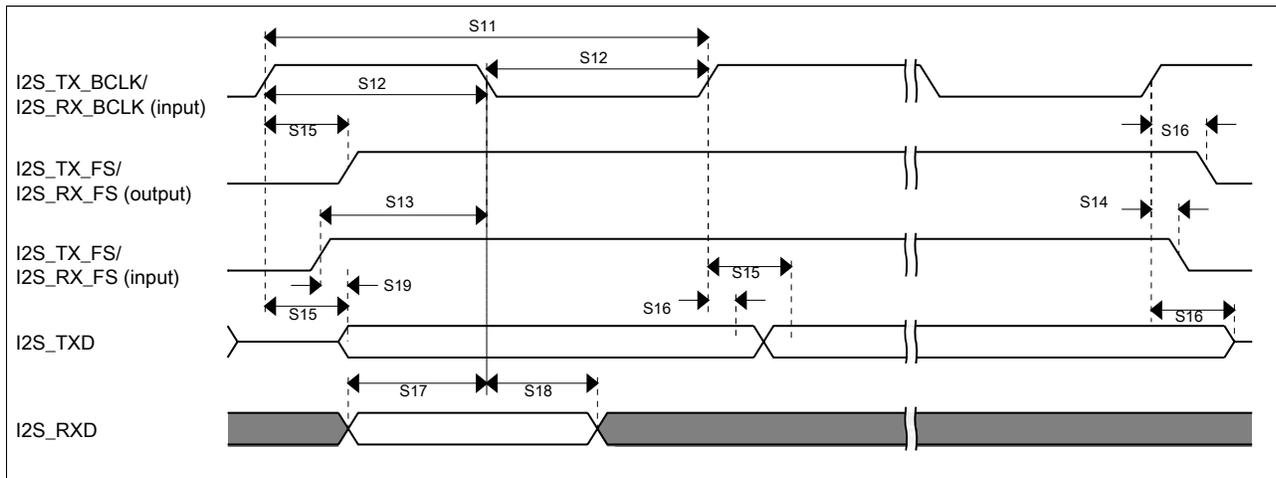


Figure 22. I2S/SAI timing — slave modes

### 3.9 Human-machine interfaces (HMI)

#### 3.9.1 LCD electrical characteristics

Table 46. LCD electricals

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f <sub>Frame</sub>	LCD frame frequency <ul style="list-style-type: none"> <li>• GCR[FFR]=0</li> <li>• GCR[FFR]=1</li> </ul>	23.3	—	73.1	Hz	
		46.6	—	146.2	Hz	
C <sub>LCD</sub>	LCD charge pump capacitance — nominal value	—	100	—	nF	
C <sub>BYLCD</sub>	LCD bypass capacitance — nominal value	—	100	—	nF	1
C <sub>Glass</sub>	LCD glass capacitance	—	2000	8000	pF	2
V <sub>IREG</sub>	V <sub>IREG</sub>				V	3
	• RVTRIM=0000	—	0.91	—		
	• RVTRIM=1000	—	0.92	—		
	• RVTRIM=0100	—	0.93	—		
	• RVTRIM=1100	—	0.94	—		
	• RVTRIM=0010	—	0.96	—		
	• RVTRIM=1010	—	0.97	—		
	• RVTRIM=0110	—	0.98	—		

Table continues on the next page...

**Table 46. LCD electricals (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li>RVTRIM=1110</li> <li>RVTRIM=0001</li> <li>RVTRIM=1001</li> <li>RVTRIM=0101</li> <li>RVTRIM=1101</li> <li>RVTRIM=0011</li> <li>RVTRIM=1011</li> <li>RVTRIM=0111</li> <li>RVTRIM=1111</li> </ul>	—	0.99	—		
$\Delta_{RTRIM}$	$V_{IREG}$ TRIM resolution	—	—	3.0	% $V_{IREG}$	
$I_{VIREG}$	$V_{IREG}$ current adder — RVEN = 1	—	1	—	$\mu A$	
$I_{RBIAS}$	RBIAS current adder <ul style="list-style-type: none"> <li>LADJ = 10 or 11 — High load (LCD glass capacitance <math>\leq 8000</math> pF)</li> <li>LADJ = 00 or 01 — Low load (LCD glass capacitance <math>\leq 2000</math> pF)</li> </ul>	—	10	—	$\mu A$	
$R_{RBIAS}$	RBIAS resistor values <ul style="list-style-type: none"> <li>LADJ = 10 or 11 — High load (LCD glass capacitance <math>\leq 8000</math> pF)</li> <li>LADJ = 00 or 01 — Low load (LCD glass capacitance <math>\leq 2000</math> pF)</li> </ul>	—	0.28	—	$M\Omega$	
VLL1	VLL1 voltage	—	—	$V_{IREG}$	V	4
VLL2	VLL2 voltage	—	—	$2 \times V_{IREG}$	V	4
VLL3	VLL3 voltage	—	—	$3 \times V_{IREG}$	V	4
VLL1	VLL1 voltage	—	—	$V_{DDA} / 3$	V	5
VLL2	VLL2 voltage	—	—	$V_{DDA} / 1.5$	V	5
VLL3	VLL3 voltage	—	—	$V_{DDA}$	V	5

- The actual value used could vary with tolerance.
- For highest glass capacitance values, LCD\_GCR[LADJ] should be configured as specified in the LCD Controller chapter within the device's reference manual.
- $V_{IREG}$  maximum should never be externally driven to any level other than  $V_{DD} - 0.15$  V
- VLL1, VLL2 and VLL3 are a function of  $V_{IREG}$  only when the regulator is enabled (GCR[RVEN]=1) and the charge pump is enabled (GCR[CPSEL]=1).
- VLL1, VLL2 and VLL3 are a function of  $V_{DDA}$  only under either of the following conditions:
  - The charge pump is enabled (GCR[CPSEL]=1), the regulator is disabled (GCR[RVEN]=0), and VLL3 =  $V_{DDA}$  through the internal power switch (GCR[VSUPPLY]=0).
  - The resistor bias string is enabled (GCR[CPSEL]=0), the regulator is disabled (GCR[RVEN]=0), and VLL3 is connected to  $V_{DDA}$  externally (GCR[VSUPPLY]=1).

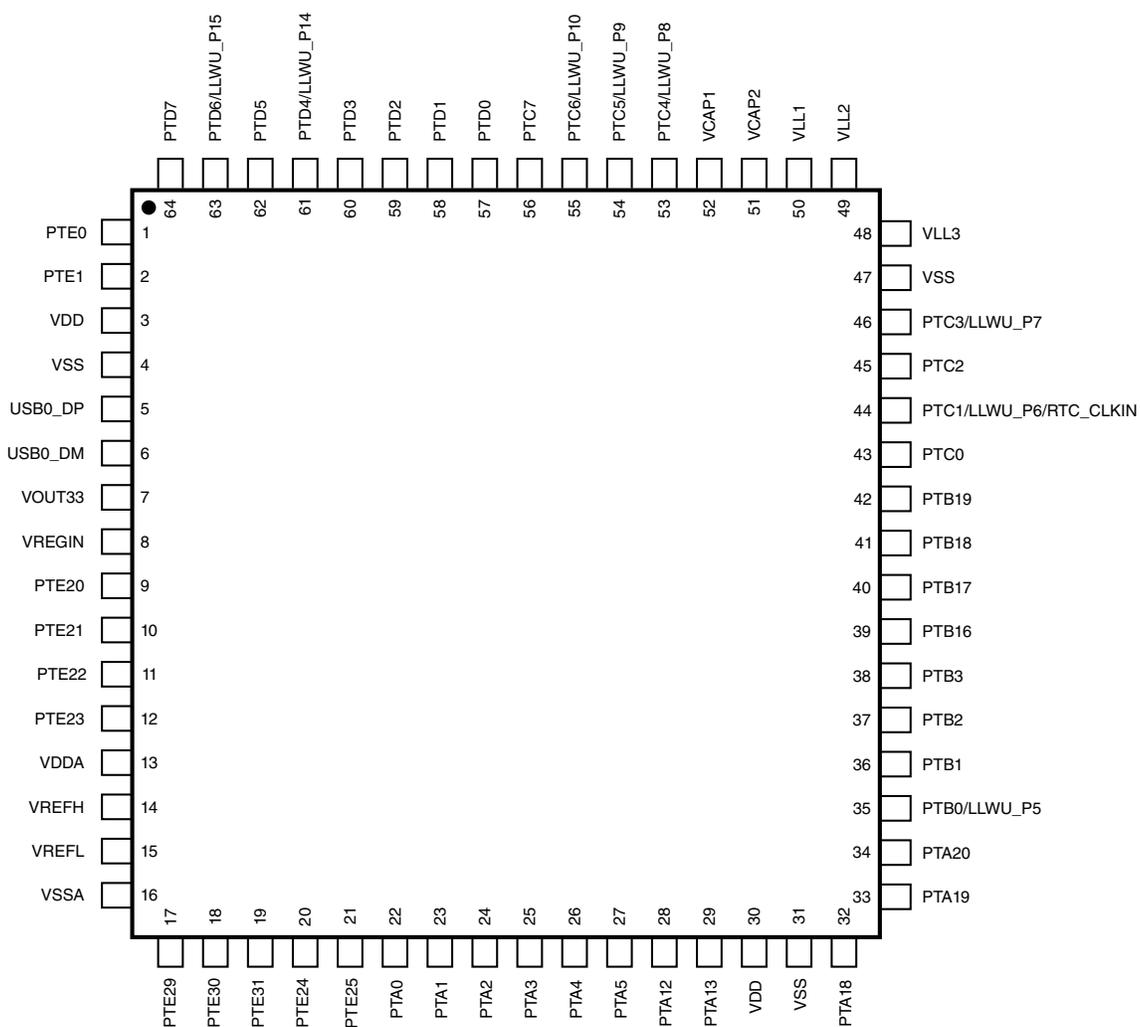
64 MAP BGA	64 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
E8	38	PTB3	LCD_P3/ ADC0_SE13	LCD_P3/ ADC0_SE13	PTB3	I2C0_SDA	TPM2_CH1				LCD_P3
E6	39	PTB16	LCD_P12	LCD_P12	PTB16	SPI1_MOSI	LPUART0_RX	TPM_CLKIN0	SPI1_MISO		LCD_P12
D7	40	PTB17	LCD_P13	LCD_P13	PTB17	SPI1_MISO	LPUART0_TX	TPM_CLKIN1	SPI1_MOSI		LCD_P13
D6	41	PTB18	LCD_P14	LCD_P14	PTB18		TPM2_CH0	I2S0_TX_BCLK			LCD_P14
C7	42	PTB19	LCD_P15	LCD_P15	PTB19		TPM2_CH1	I2S0_TX_FS			LCD_P15
D8	43	PTC0	LCD_P20/ ADC0_SE14	LCD_P20/ ADC0_SE14	PTC0		EXTRG_IN	audioUSB_SOF_OUT	CMP0_OUT	I2S0_TXD0	LCD_P20
C6	44	PTC1/ LLWU_P6/ RTC_CLKIN	LCD_P21/ ADC0_SE15	LCD_P21/ ADC0_SE15	PTC1/ LLWU_P6/ RTC_CLKIN	I2C1_SCL		TPM0_CH0		I2S0_TXD0	LCD_P21
B7	45	PTC2	LCD_P22/ ADC0_SE11	LCD_P22/ ADC0_SE11	PTC2	I2C1_SDA		TPM0_CH1		I2S0_TX_FS	LCD_P22
C8	46	PTC3/ LLWU_P7	LCD_P23	LCD_P23	PTC3/ LLWU_P7	SPI1_SCK	LPUART1_RX	TPM0_CH2	CLKOUT	I2S0_TX_BCLK	LCD_P23
E3	47	VSS	VSS	VSS							
E4	—	VDD	VDD	VDD							
C5	48	VLL3	VLL3	VLL3							
A6	49	VLL2	VLL2	VLL2/ LCD_P4	PTC20						LCD_P4
B5	50	VLL1	VLL1	VLL1/ LCD_P5	PTC21						LCD_P5
B4	51	VCAP2	VCAP2	VCAP2/ LCD_P6	PTC22						LCD_P6
A5	52	VCAP1	VCAP1	VCAP1/ LCD_P39	PTC23						LCD_P39
B8	53	PTC4/ LLWU_P8	LCD_P24	LCD_P24	PTC4/ LLWU_P8	SPI0_SS	LPUART1_TX	TPM0_CH3	I2S0_MCLK		LCD_P24
A8	54	PTC5/ LLWU_P9	LCD_P25	LCD_P25	PTC5/ LLWU_P9	SPI0_SCK	LPTMR0_ALT2	I2S0_RXD0		CMP0_OUT	LCD_P25
A7	55	PTC6/ LLWU_P10	LCD_P26/ CMP0_IN0	LCD_P26/ CMP0_IN0	PTC6/ LLWU_P10	SPI0_MOSI	EXTRG_IN	I2S0_RX_BCLK	SPI0_MISO	I2S0_MCLK	LCD_P26
B6	56	PTC7	LCD_P27/ CMP0_IN1	LCD_P27/ CMP0_IN1	PTC7	SPI0_MISO	audioUSB_SOF_OUT	I2S0_RX_FS	SPI0_MOSI		LCD_P27
C3	57	PTD0	LCD_P40	LCD_P40	PTD0	SPI0_SS		TPM0_CH0		FXIO0_D0	LCD_P40
A4	58	PTD1	LCD_P41/ ADC0_SE5b	LCD_P41/ ADC0_SE5b	PTD1	SPI0_SCK		TPM0_CH1		FXIO0_D1	LCD_P41
C2	59	PTD2	LCD_P42	LCD_P42	PTD2	SPI0_MOSI	UART2_RX	TPM0_CH2	SPI0_MISO	FXIO0_D2	LCD_P42
B3	60	PTD3	LCD_P43	LCD_P43	PTD3	SPI0_MISO	UART2_TX	TPM0_CH3	SPI0_MOSI	FXIO0_D3	LCD_P43
A3	61	PTD4/ LLWU_P14	LCD_P44	LCD_P44	PTD4/ LLWU_P14	SPI1_SS	UART2_RX	TPM0_CH4		FXIO0_D4	LCD_P44
C1	62	PTD5	LCD_P45/ ADC0_SE6b	LCD_P45/ ADC0_SE6b	PTD5	SPI1_SCK	UART2_TX	TPM0_CH5		FXIO0_D5	LCD_P45

## Pinouts and Packaging

64 MAP BGA	64 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
B2	63	PTD6/ LLWU_P15	LCD_P46/ ADC0_SE7b	LCD_P46/ ADC0_SE7b	PTD6/ LLWU_P15	SPI1_MOSI	LPUART0_RX		SPI1_MISO	FXIO0_D6	LCD_P46
A2	64	PTD7	LCD_P47	LCD_P47	PTD7	SPI1_MISO	LPUART0_TX		SPI1_MOSI	FXIO0_D7	LCD_P47

## 5.2 KL43 Family Pinouts

Figure below shows the 64 LQFP pinouts



**Figure 23. 64 LQFP Pinout diagram**

Figure below shows the 64 MAPBGA pinouts